Electronic Structure and Chemical Bonding

David J. Singh Oak Ridge National Laboratory



Chemical bonding is about the rearrangement of electrons due to the arrangement of the nuclei.

It is the source of the interesting properties of condensed matter.

But how do we characterize it?

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How Do We Know What is What



Note: An expansion in radial functions times spherical harmonics is complete \rightarrow Expansion about more than one site is over-complete (ambiguous).

What Follows is Qualitative

An Example: Two Titanium Oxides TiO₂ Ti_2O_3

Both have Ti octahedrally coordinated by O.

A Chemist's View





Electronegativity:

Ti: 1.54 O: 3.44 Large difference means O is O²⁻ and therefore we have Ti⁴⁺ and Ti³⁺ respectively. These are known common valence states of Ti.



Things are not always so simple:

- Smaller electronegativity differences (e.g. BaFe₂As₂).
- Metals (e.g. PdCoO₂).
- Multiple mixed valence ions (e.g. MnFe₂O₄ – Mn²⁺Fe³⁺; Mn⁴⁺Fe²⁺ etc.).

First Thought: Charges in Spheres

LAPW calculation with $r_{Ti}=2.0$ bohr, $r_{O}=1.6$ bohr.

per Ti	TiO ₂	Ti_2O_3
Ti	19.415 e	19.513 e
Ο	7.225 e	7.225 e
Interstitial	4.135 e	3.645 e

Difference in Ti sphere charge is less than 0.1 e !

Effect of *"screening"*, in other words orbitals breath as the occupation is changed due to effect of e-e Coulomb repulsion. Also, *sp* charge moves due to changes in covalency.

Density of States for TiO₂

LAPW calculation with $r_{Ti}=2.0$ bohr, $r_{O}=1.6$ bohr



Density of States for Ti₂O₃

LAPW calculation with $r_{Ti}=2.0$ bohr, $r_{O}=1.6$ bohr



N(E) per Ti

Comparison of Ti d Projections



Ti d Projections with 3 eV Shift



Ti d DOS per Ti

Deep Core Level Positions

- Reflect the Coulomb potential, which should vary with valence.
- Experimentally accessible quantities.
- Absolute position is arbitrary in a solid state calculation: Need to look either at differences or relative to some physical reference, e.g. Fermi level.

O 1s – Ti 1s (PBE GGA). TiO₂: 4357.73 eV Ti₂O_{3:} 4356.09 eV

- Difference is > 1 eV and can be used to characterize valence. However, the differences in non-oxides/halides are smaller, and this is indirect (relies on reference compounds).
- Higher binding energy for metal ion means higher valence.
- Can be misleading for hypothetical crystal structures.

What Can Be Done for TiO₂ / Ti₂O₃

• Do DFT calculations; find band characters and then count.



12 O p bands occupied (24 e) per cell (Ti₂O₄), no occupied d bands \rightarrow Ti⁴⁺ 18 O *p* bands occupied (36 *e*) per cell (Ti₄O₆), 2 occupied *d* bands \rightarrow Ti³⁺

Another Example (Hydrides)

Hydrogen is exceptionally flexible and important.

- Cation: H⁺ (proton, e.g. in fuel cells, acids).
- Anion: H⁻ (e.g. LiH).
- Metallic (PdH).
- Covalent: e.g. hydrocarbons.

Can have very short bond-lengths:

• O-H ~0.95 Å, C-H ~1.1 Å.





Hydrogen powered lawn mower (K. Yvon).

Charge Density



Du et al., 2009 (H in anion vacancies of semiconductors)

Case Study



Journal of Allovs and Compounds 306 (2000) 127-132

www.elsevier.com/locate/jallcom

Journal of ALLOYS AND COMPOUNDS

Trigonal SrAl₂H₂: the first Zintl phase hydride

F. Gingl^a, T. Vogt^b, E. Akiba^{a,*}

Angewandte Chemie

Semiconductor Materials

DOI: 10.1002/anie.200502090

SrAlSiH: A Polyanionic Semiconductor Hydride**

Thomas Björling, Dag Noréus, Kjell Jansson, Magnus Andersson, Ekaterina Leonova, Mattias Edé Ulf Hålenius, and Ulrich Häussermann*

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Discovery of a family of new hydride compounds, possibly with very interesting bonding. *What does DFT say about it?*

JACS ARTICLES Published on Web 12/31/2005

Polyanionic Hydrides from Polar Intermetallics AeE_2 (Ae = Ca, Sr, Ba; E = Al, Ga, In)

Thomas Björling,[‡] Dag Noréus,[‡] and Ulrich Häussermann*,^{†,§}

Zintl Compounds

- Valence precise compounds based on:
- (1) electro-positive elements that donate charge.
- (2) polyanions, with bonding satisfied by the added charge.

Example: Na₂Tl

- Na donates charge to TI.
- Structure based on (Tl₄)⁸⁻ tetrahedral polyanions.
- TI (group IIIB) then forms a bonding pattern characteristic of a group VB element such as P.

* Image from http://ruby.chemie.uni-freiburg.de/Vorlesung/intermetallische_0.html





Structure – SrAl₂H₂





Sr²⁺ electropositive ion. Al₂H₂ polyanionic framework (note Al-H bonds in drawing).

F. Gingl et al. / Journal of Alloys and Compounds 306 (2000) 127–132

Structure (drawn without bonds)



Charge Density





SrGa₂



Bjorling, 2005 – interpreted this as covalency between H and Ga

Charge Density - SrAISiH



Subedi argued that this was covalent bonding of Si and Al, but ionic H⁻

DOS: SrAISiH (semiconductor)



Subedi et al., 2008

SrAl₂H₂



N(E)

Simplest Covalency







What is the Nature of Bonding of H

Charge

- DOS plot was based on LAPW calculations with a H sphere radius of 1 bohr.
- Charge inside H sphere for SrAISiH was 0.46 e.
- Charge inside the same radius for a stabilized H⁻ is 0.48 e, which is similar.
- Charge inside sphere is at least consistent with anionic H, which therefore can be considered as a possible alternative to covalent AI-H bonding.

SrAISiH and Hypothetical KAISi



Symbol size proportional to Al *p* character

SrAISi and Hypothetical SrAISiF

SrAlSiF (hypothetical)

F has highest electronegativity of any element.

SrAlSi

10.0 8.0 6.0 4.0 2.0 0.0 EF E(eV) 2000000000 000000 -2.0^{°°°°°°} ,000°° -4.0 and -6.0 **F***p* -8.0 Si s -10.0Σ K Σ Κ M ٨ M Λ Г Δ

Symbol size proportional to Al p character

Interpretation





Ga Compounds



Plotting symbol size is based on Ga *p* contribution.

Qualitative Conclusion

- Sr, Ba are divalent cations (donate charge).
- H occurs as H⁻ (anion) in these compounds (takes charge, not covalent).
- Polyanionic framework is based on Si, Al, Ga these behave like C in forming graphite like sheets with sp² bonding (Zintl concept).

Remarks

- Descriptions of bonding and charge state are invariably qualitative, but they are exceedingly useful in understanding materials.
- Sorting them out often requires a lot of "hand-work" and testing of different alternatives.